

ABSTRACT OF THE DISCLOSURE

A liquid-crystal display device is provided wherein large
5 electrostatic capacitance can be obtained without exposure of
a metal film on a surface of a TFT array substrate, and yield
in production and stability in images are improved. In the
liquid-crystal display device of the present invention, a
thin-film transistor section is mounted which is used to
10 selectively connect either of a data wiring formed on a gate
insulating film or a transparent electrode by a gate connected
to an address wiring placed in each of picture element areas.
In each of picture element areas, a capacitor section is formed
with a first electrode formed, on the gate insulating film,
15 using the same conductive film as used for the data wiring and
a second electrode formed, on an upper layer insulating film
formed on the gate insulating film, using the same transparent
conductive film as used for a transparent electrode.

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